GaAlAs-IR-Lumineszenzdioden (880 nm) in SMR® Gehäuse
GaAlAs Infrared Emitters (880 nm) in SMR® Package

SFH 4580
SFH 4585

SFH 4580

SFH 4585

Wesentliche Merkmale

- GaAlAs-LED mit sehr hohem Wirkungsgrad
- SMR® (Surface Mount Radial) Gehäuse
- Für Oberflächenmontage geeignet
- Gegurtet lieferbar
- Gehäusegleich mit Fotodiode SFH 2500/ SFH 2505
- Hohe Zuverlässigkeit
- Gute spektrale Anpassung an Si-Fotoempfänger
- UL-Freigabe

Features

- Very highly efficient GaAlAs-LED
- SMR® (Surface Mount Radial) package
- Suitable for surface mounting (SMT)
- Available on tape and reel
- Same package as photodiode SFH 2500/ SFH 2505
- High reliability
- Spectral match with silicon photodetectors
- UL-approval

Anwendungen

- IR-Fernsteuerung von Fernseh- und Rundfunkgeräten, Videorecordern, Lichtdimmern
- Gerätefernsteuerungen für Gleich- und Wechsellichtbetrieb
- Sensorik
- Diskrete Lichtschranken
- Diskrete Optokoppler

Applications

- IR remote control of hi-fi and TV-sets, video tape recorders, dimmers
- Remote control for steady and varying intensity
- Sensor technology
- Discrete interrupters
- Discrete optocouplers

Typ **Type**	**Bestellnummer** **Ordering Code**	**Strahlstärkegruppierung** [1] (I_F = 100mA, t_p = 20 ms) **Radiant intensity grouping** [1] I_e (mW/sr)
SFH 4580	Q62702-P1806	≥ 25
SFH 4585	Q62702-P1799	

[1] gemessen bei einem Raumwinkel Ω = 0.01 sr
measured at a solid angle of Ω = 0.01 sr

Grenzwerte (T_A = 25 °C)
Maximum Ratings

Bezeichnung **Parameter**	**Symbol** **Symbol**	**Wert** **Value**	**Einheit** **Unit**
Betriebs- und Lagertemperatur Operating and storage temperature range	T_{op}; T_{stg}	– 40 … + 100	°C
Sperrspannung Reverse voltage	V_R	5	V
Durchlaßstrom Forward current	I_F	100	mA
Stoßstrom, t_p = 10 µs, D = 0 Surge current	I_{FSM}	2.5	A
Verlustleistung Power dissipation	P_{tot}	200	mW
Wärmewiderstand, freie Beinchenlänge max. 10 mm Thermal resistance, lead length between package bottom and PC-board max. 10 mm	R_{thJA}	375	K/W

Kennwerte (T_A = 25 °C)
Characteristics

Bezeichnung **Parameter**	**Symbol** **Symbol**	**Wert** **Value**	**Einheit** **Unit**
Wellenlänge der Strahlung Wavelength at peak emission I_F = 100 mA	λ_{peak}	880	nm
Spektrale Bandbreite bei 50% von I_{rel} Spectral bandwidth at 50% of I_{rel} I_F = 100 m A	$\Delta\lambda$	80	nm
Abstrahlwinkel Half angle	φ	± 15	Grad deg.
Aktive Chipfläche Active chip area	A	0.09	mm^2
Abmessungen der aktiven Chipfläche Dimension of the active chip area	$L \times B$ $L \times W$	0.3 × 0.3	mm
Abstand Chipoberfläche bis Linsenscheitel Distance chip front to lens top	H	3.9 … 4.5	mm

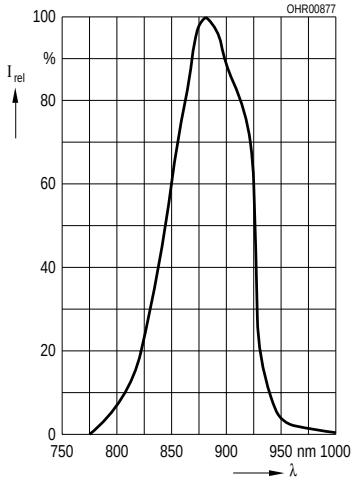
Kennwerte (T_A = 25 °C)
Characteristics (cont'd)

Bezeichnung **Parameter**	**Symbol** **Symbol**	**Wert** **Value**	**Einheit** **Unit**
Schaltzeiten, I_e von 10% auf 90% und von 90% auf 10%, bei I_F = 100 mA, R_L = 50 Ω Switching times, I_e from 10% to 90% and from 90% to 10%, I_F = 100 mA, R_L = 50 Ω	t_r, t_f	0.6/0.5	µs
Kapazität Capacitance V_R = 0 V, f = 1 MHz	C_o	15	pF
Durchlaßspannung, Forward voltage I_F = 100 mA, t_p = 20 ms I_F = 1 A, t_p = 100 µs	 V_F V_F	 1.50 (≤ 1.8) 3.00 (≤ 3.8)	 V V
Sperrstrom, Reverse current V_R = 5 V	I_R	0.01 (≤ 1)	µA
Gesamtstrahlungsfluß, Total radiant flux I_F = 100 mA, t_p = 20 ms	Φ_e	25	mW
Temperaturkoeffizient von I_e bzw. Φ_e, I_F = 100 mA Temperature coefficient of I_e or Φ_e, I_F = 100 mA	TC_I	– 0.5	%/K
Temperaturkoeffizient von V_F, I_F = 100 mA Temperature coefficient of V_F, I_F = 100 mA	TC_V	– 2	mV/K
Temperaturkoeffizient von λ, I_F = 100 mA Temperature coefficient of λ, I_F = 100 mA	TC_λ	0.25	nm/K

Strahlstärke I_e in Achsrichtung
gemessen bei einem Raumwinkel Ω = 0.01 sr
Radiant Intensity I_e in Axial Direction
at a solid angle of Ω = 0.01 sr

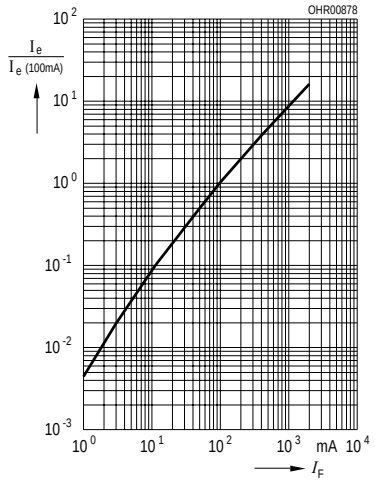
Bezeichnung **Parameter**	**Symbol**	**Wert** **Value**	**Einheit** **Unit**
Strahlstärke Radiant intensity I_F = 100 mA, t_p = 20 ms	$I_{e\ min}$	≥ 25	mW/sr
Strahlstärke Radiant intensity I_F = 1 A, t_p = 100 µs	$I_{e\ typ}$	225	mW/sr

Relative Spectral Emission
$I_{rel} = f(\lambda)$

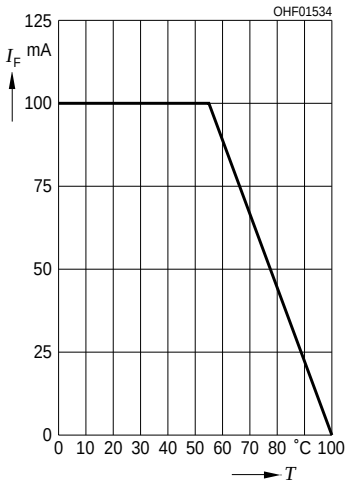


Radiant Intensity $\frac{I_e}{I_e\ 100\ mA} = f(I_F)$

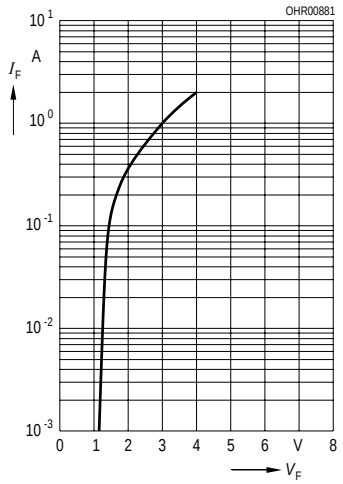
Single pulse, t_p = 20 µs



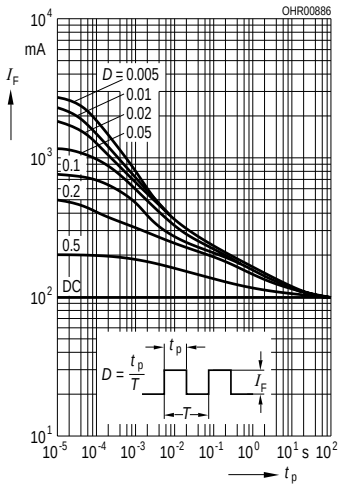
Max. Permissible Forward Current
$I_F = f(T_A)$



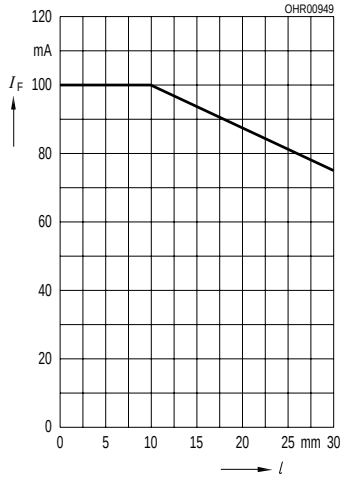
Forward Current
$I_F = f(V_F)$, single pulse, t_p = 20 µs



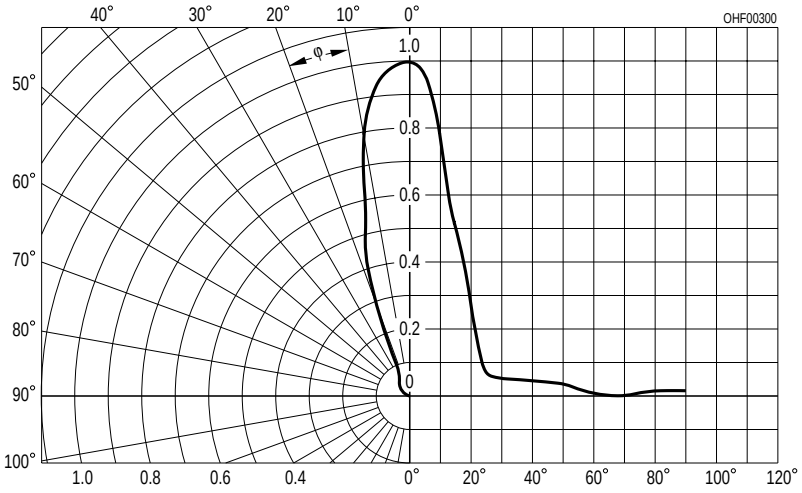
Permissible Pulse Handling Capability $I_F = f(\tau)$, T_A = 25 °C, duty cycle D = parameter



Forward Current vs. Lead Length between the Package Bottom and the PC-Board $I_F = f(l)$, T_A = 25 °C

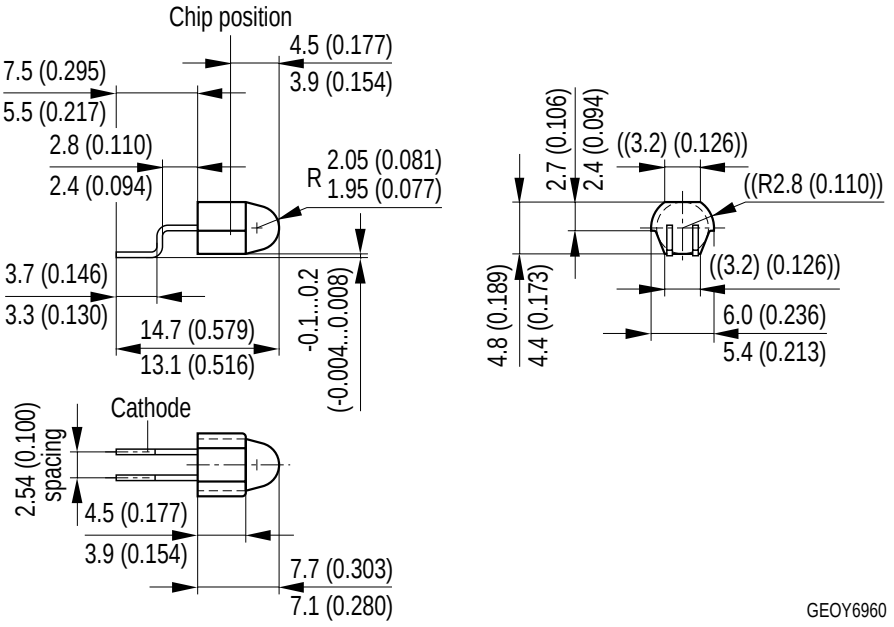


Radiation Characteristics $I_{rel} = f(\varphi)$

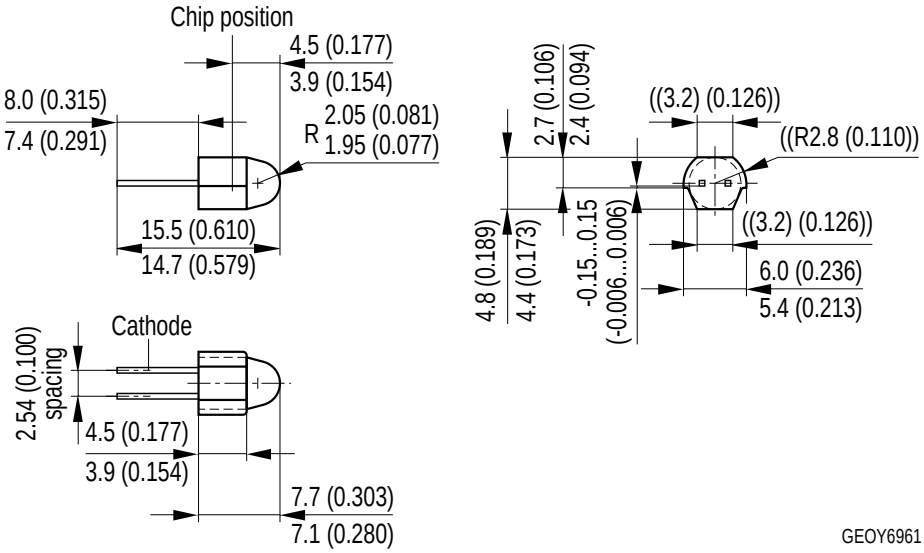


Maßzeichnung
Package Outlines

SFH 4580



SFH 4585



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

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